



500.39912CX1

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: T. IWASAKI, et al.
Application No.: 10/611,862
Filed: July 3, 2003
For: SEMICONDUCTOR DEVICE WITH MULTILAYER
CONDUCTIVE STRUCTURE FORMED ON A
SEMICONDUCTOR SUBSTRATE
Art Unit: 2813
Examiner: S. W. Smoot

AMENDMENT

Commissioner for Patents
P.O. BOX 1450
Alexandria, VA 22313-1450

June 7, 2005

Sir:

In response to the Office Action dated March 7, 2005, please amend the above-identified application as listed below and as set forth on the following pages:

Amendments to the Claims;

Remarks follow the amendments; and

Appendix A includes Sworn Translation of Japanese Patent Appln.

11-006108, filed January 13, 1999.